

Measurements and Characterization Division Photovoltaic Cell Measurements Request Form

Confidential (protection available only to USA requesters

Pequester and Correspondence	adonco Informati	on			
Requester and correspondence information Demoster above					
Requester Affiliation	K	. Requester phone			
Cover latter? V/N Begueste		_ Kequesion fax of email			
Other persons outhorized to receive	$\frac{1}{1}$ s usual supplied $\frac{1}{1}$	$\frac{l/N}{l}$ wFO task number (II wFO)			
Other persons authorized to receive data and test report					
If other then requestor					
Technical contact person and contact information					
Deliver data to Return sample to					
Sample information (please use one form for each material/structure)					
Manufacturer Device IDs					
Property of (if other than Mfr)					
World record expected? $\underline{Y/N}$	Number of jun	ctions $\frac{1/2/3/4}{2}$		— , —,	
Has this cell been previously measured	red in this lab? $\Box Y$	es \rightarrow When_			Don't know
Please circle junctions below. Do not indicate windows, AR coatings, or contacts. If you wish to have					
these or other features indicated on the test report, please note them in the comment section, below.					
Mono-Si a-Si/multi-Si GaAs GaInP/GaAs/Ge Triple ZnO/CdTe					
Multi-Si CdS/C	dTe C	aAs/Ge Tand	em Ge		$ZnO/Cu(In Ga)Se^2$
a-Si CdS/C	u(In Ga)(S Se)	aInAs	nano-ci	rystalline	ZnO/CuInSe2
a-Si/a-Si CdS/C	u(In Ga)Se2	aInAs/GaAs	Hetero-i solid na	ano-crystalline	
a-Si/a-Si [·] Ge CdS/C	uInSe2	aInP	sonum		□other III/V
a-Si/a-Si/a-Si:Ge GaAlA	s/GaAs Tandem	GaInP/GaAs H	etero-i		Other II/VI
a-Si/a-Si:Ge/a-Si:Ge GaAlA	s/GaAs Hetero-i	aInP/GaAs T	andem		Tother
Requester's data	Area Isc	J	sc Voc	FF	Eff.
QE/LIV Global Performance Quantum Efficiency and current vs. voltage under AM1.5 global normal spectral irradiance					
(1000 W/m ² , AS1M E892-87, IEC 904-3) at 25°C.					
\Box QE/LIV Concentrator Performance Quantum Efficiency and current vs. voltage under AM1.5 direct normal spectral irradiance					
(1000 W/m, AOD 0.085) at 25°C. DW Dark surrout as a solver P_{1} Dark surrout P_{2} Dark surrout V (surrout)					
DIV Dark current vs. voltage Don't exceed: <u>A</u> , <u>V(forward)</u> , <u>V(reverse)</u> .					
$\Box \qquad \text{Kelefence cell Calloration Cultern at Zero Volts / Voltage}$					
OTHED (norometer v. temperature biog rate or irrediance non standard reporting conditions)					
Priority	Sample identification or contacting diagram				
(This section is to be completed only by				indoning diagra	
Tom Moriarty or Keith Emery)					
Normal (2 to 5 weeks multijunction					
devices take longer)	nanajanotion				
\square Rush By					
□ Now	<u> </u>			Use b	ack of form if necessarv
Other Netes or Instruction					,
	Destel Address	Cont	act Information	Dhana	omoil
PV Cell Performance Laboratory PV Cell Performance Laboratory			act mormation ratory	(303) 384-6458	eman
Tom Moriarty, NREL, SERF, Lab E220	Tom Moriarty, NREL, MS 3	215 Tom I	Moriarty	(303) 384-6551	tom_moriarty@nrel.gov
16253 Denver West Parkway	1617 Cole Blvd.	Keith	Emery (team leader)	(303) 384-6632	keith_emery@nrel.gov
Golden, CO 80401-3393 USA Golden, CO 80401-3393 USA NREL PV Website: http://www.hrel.gov/pv					
Date Received	Authorization to Pr	oceed			
Date Reviewed Reviewer's Initials		Date shinned or returned			
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